

2.GHz Fixed Modulus Frequency Synthesiser

DS3966-2.2 May 996

The SP5070 is a single modulus frequency synthesiser for use in Satellite TV receivers and together with an appropriate voltage controlled oscillator (VCO), forms a complete phase locked loop (PLL) synthesiser. The circuit consists of a prescaler with preamplifier and a fixed modulus divider. The phase comparator is fed with a reference frequency derived from an external oscillator or crystal. The comparator has a charge pump output amplifier stage around which feedback may be applied. Only an external transistor is required for varicap line driving.

FEATURES

- Low Power Consumption (5V, 47mA typ.)
- Prescaler and Preamplifier Included
- Charge Pump Amplifier with Feedback Point
- Charge Pump Disable Facility
- Synthesises Frequencies up to 2.4GHz
- Pin and Function Compatible with SP5060 and SP5062
- Full ESD Protection*
 * Normal ESD handling procedures should be observed.

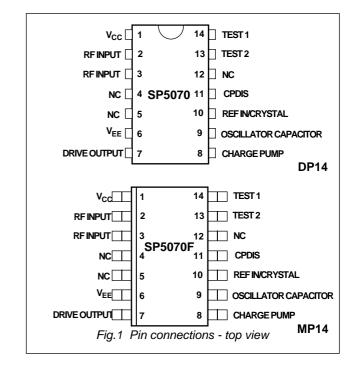
APPLICATIONS

- Satellite TV
- High IF Cable Tuning Systems
- C-Band with Frequency Doubling Mixer

ORDERING INFORMATION

SP5070 DP - (14 Lead Plastic Package)

SP5070F MP - (14 Lead Miniature Plastic Package)



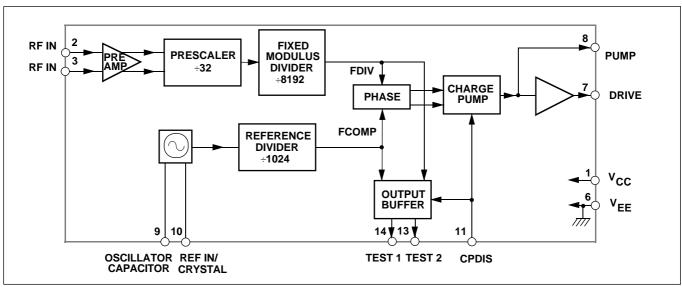


Fig.2 Block diagram of SP5070

SP5070

ELECTRICAL CHARACTERISTICS

Tamb = -40°C to +85°C,VCC = +4.5V to +5.5V. These characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage ranges unless otherwise stated.

Characteristics	Cumbal	Din	Value			Units	O a maliti a ma	
Characteristics	Symbol	Pin	Min	Тур	Max	Units	Conditions	
Supply current	I _{CC}	1	-	47	55	mA	V _{CC} = 5V	
Prescaler input voltage Prescaler input voltage		2,3 2,3	50 100	-	300 300	${\rm mV_{RMS} \atop mV_{RMS}}$	300MHz to 1.8GHz sinewave 2.4GHz, see Fig.5	
Prescaler input impedance Input capacitance		2,3 2,3	-	50 2	-	pF		
Charge pump output current Charge pump output leakage Drift due to leakage Charge pump drive output current		8 8 - 7	- - -	±100 - -	- ±5 5	μΑ nA mV/s mA	V pin 8 = 2.0V V pin 8 = 2.0V At collector of External Varicap Drive transistor V pin 7 = 0.7V	
Charge pump amplifier gain		-	-	6400	-	-	pin 7 current 100μa	
Oscillator temperature stability Oscillator stability with supply voltage		9,10 9,10		-	2 2	ppm/°C ppm/V		
Reference clock frequency External reference amplitude		10 10	2 150	-	10 500	MHz mV _{RMS}		
Charge pump disable/TEST 1 and TEST 2/enable		11	-250	-	-500	μΑ	V _{IN} <0V	
Charge pump disable leakage		11	-	-	10	μA	V pin 11= V _{CC}	
TEST 1/TEST 2 sink current		13,14	1	-	-	mA	VOUT = 0.7V	
TEST 1/TEST 2 leakage current		13,14	-	-	10	μA	VOUT = V _{CC} +0.3V	
TEST 1/TEST 2 voltage		13,14	-	-	V _{CC} +0.3	V		

ABSOLUTE MAXIMUM RATINGS

All voltages are referred to $V_{EE} = 0V$

		V			
Characteristics	Pin	Min	Max	Units	
Supply voltage	1	-0.3	7	V	
RF input voltage	2,3	-	2.5	Vp-p	
RF input DC offset	2,3	-0.3	V _{CC} +0.3	V	
Charge pump DC offset	8	-0.3	V _{CC} +0.3	V	
Charge pump disable	11	-0.7	V _{CC} +0.3	V	
Drive DC offset	7	-0.3	V _{CC} +0.3	V	
Crystal oscillator DC offset	9,10	-0.3	V _{CC} +0.3	V	
TEST outputs	13,14	-0.3	V _{CC} +0.3	V	
Storage temperature	-	-55	150	°C	
Junction temperature	-	-	+150	°C	
DP14 thermal resistance, chip-to-ambient	-	-	78	°C/W	
DP14 thermal resistance, chip-to-case	-	-	30	°C/W	
MP14 thermal resistance, chip-to-ambient	-	-	123	°C/W	
MP14 thermal resistance, chip-to-case	-	-	45	°C/W	
Power consumption at 5.5V	-	-	275	mW	

FUNCTIONAL DESCRIPTION

The SP5070, when used with a voltage controlled oscillator, forms a complete phase locked loop frequency synthesiser.

The phase comparator comparison frequency is obtained by dividing the reference frequency. This may be generated on-chip by means of an external crystal, or from an external reference oscillator.

The output of the prescaler is divided by the fixed modulus divider, producing an output frequency which is phased locked to the comparison frequency.

The divider stages are arranged to give a fixed ratio between the synthesised frequency and the reference of 256:1. Any frequency within the range of 300MHz to 2.4GHz may be achieved by using the appropriate reference or crystal frequency.

A single external transistor, driven from the charge pump output, provides the output drive necessary for the oscillator varicap line.

A test facility which disables the charge pump is also provided. This is activated when a negative voltage is applied to pin 11, see electrical characteristics above. When the device is in this mode, F_{COMP} and F_{DIV} are also available at outputs TEST1 and TEST2 respectively. These are open collector outputs and are each capable of sinking a minimum of 1mA. In normal mode of operation these outputs are high impedance.

 $\dot{}$ For compatibility with SP5060/SP5062, pin 11 may be connected to V $_{CC}$

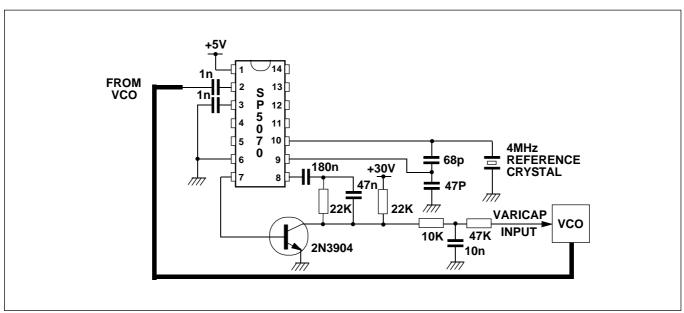


Fig.3 Typical application and test circuit (1024MHz with 4MHz reference crystal)

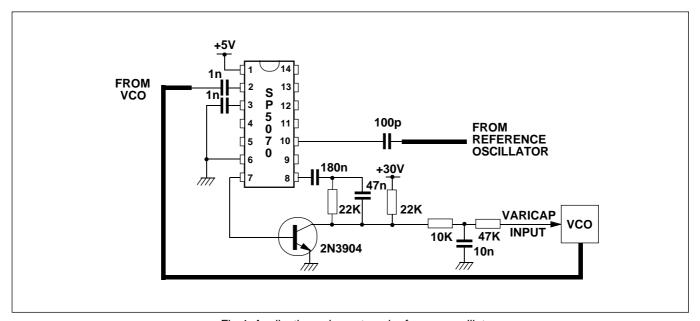
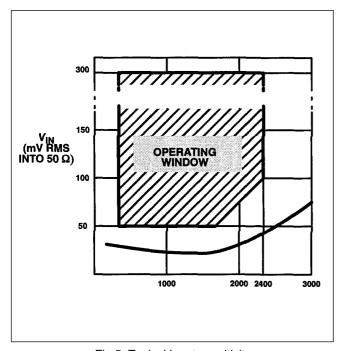


Fig.4 Application using external reference oscillator

SP5070



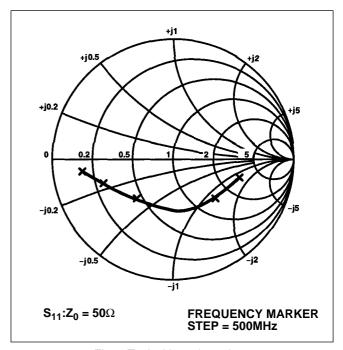


Fig.5 Typical input sensitivity

Fig.6 Typical input impedance

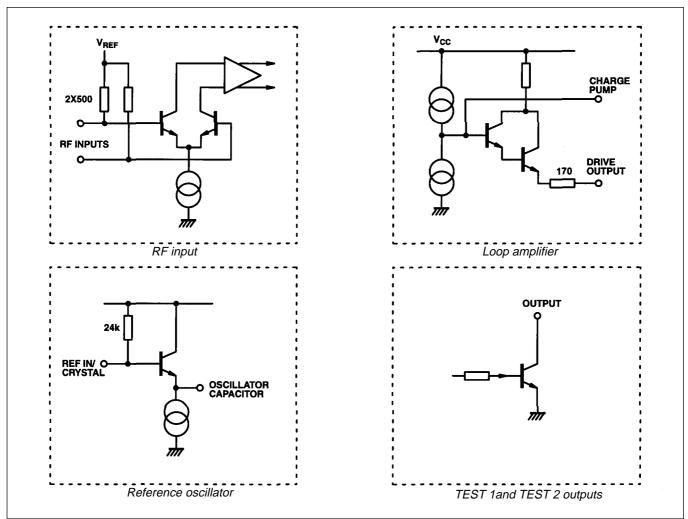
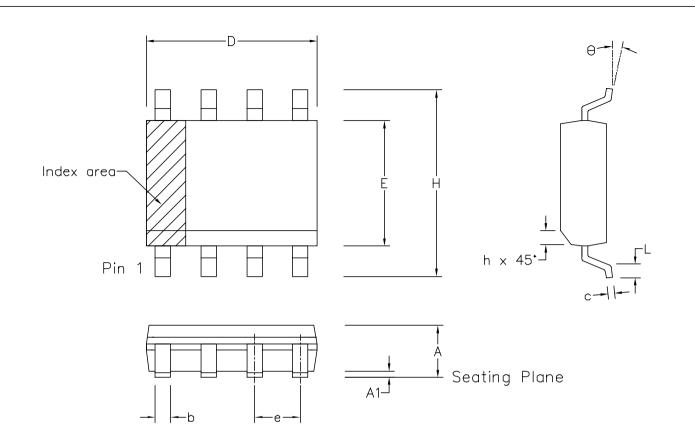


Fig.7 SP5070 input/output interface circuits



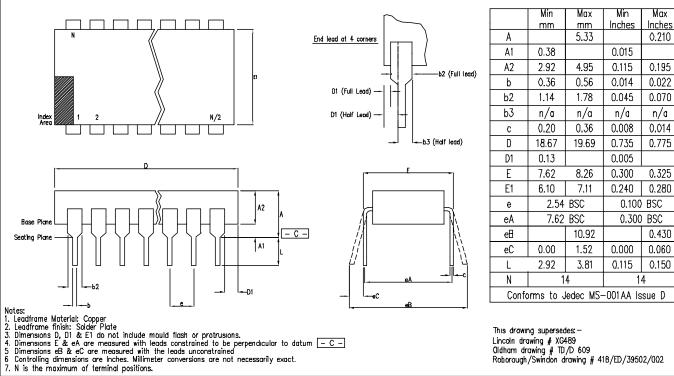
	Min	Max	Min	Max				
	mm	mm	inch	inch				
Α	1.35	1.75	0.053	0.069				
A1	0.10	0.25	0.004	0.010				
D	8.55	8.75	0.337	0.344				
Н	5.80	6.20	0.228	0.244				
E	3.80	4.00	0.150	0.157				
L	0.40	1.27	0.016	0.050				
е	1.27	BSC	0.050 BSC					
b	0.33	0.51	0.013	0.020				
С	0.19	0.25	0.008	0.010				
0	0 0	8 °	0°	8°				
h	0.25	0.50	0.010	0.020				
	Pin Features							
N	1	4	14					

Notes:

- 1. The chamfer on the body is optional. If it not present, a visual index feature, e.g. a dot, must be located within the cross—hatched area.
- 2. Controlling dimension are in inches.

- 3. Dimension D do not include mould flash, protusion or gate burrs. These shall not exceed 0.006" per side.
 4. Dimension E1 do not include inter—lead flash or protusion. These shall not exceed 0.010" per side.
 5. Dimension b does not include dambar protusion/intrusion. Allowable dambar protusion shall be 0.004" total in excess of b dimension.

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ISSUE	1	2	3	4				Title: Package Outline Drawing for 14 Ids SOIC(N)-0.150" Body Width (MP)	
ACN	006745	201937	202596	203707		 	SEMICONDUCTOR	14 Ids SUIC(N)—0.130 Body Width (MP)	
DATE	7APR95	27FEB97	12JUN97	9DEC97				Drawing Number	
APPROVED								GPD00011	



This drawing supersedes: -	
Lincoln drawing # XG489 Oldham drawing # TD/D 609	
Roboraugh/Swindon drawing #	41B/ED/39502/002

Max

n/a

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ISSUE	1							
ACN	202539							
DATE	23MAY97							

APPROVED

MITEL SEMICONDUCTOR

Title: 14 Lead Plastic DIP Outline Drawing

Drawing Number

ORIGINATING SITE: Swindon

GPD00344



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World Headquarters - Canada

Tel: +1 (613) 592 2122 Fax: +1 (613) 592 6909

Asia/Pacific

Tel: +65 333 6193 Fax: +65 333 6192 Europe, Middle East, and Africa (EMEA)

Tel: +44 (0) 1793 518528 Fax: +44 (0) 1793 518581

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North America

Tel: +1 (770) 486 0194

Fax: +1 (770) 631 8213